

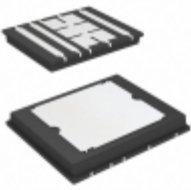

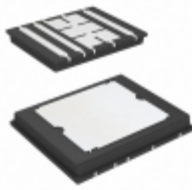
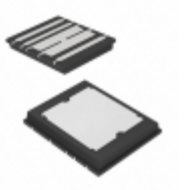

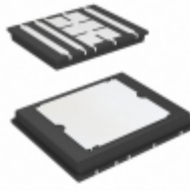
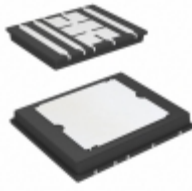
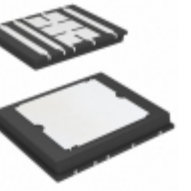
	<h2>SIE848DF-T1-E3</h2>
	<p>Hersteller-Teilenummer: SIE848DF-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 60A POLARPAK</p> <p>Datenblätter:  SIE848DF-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1688 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIE848DF-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 60A POLARPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1688 pcs Stock
detaillierte Beschreibung	N-Channel 30V 60A (Tc) 5.2W (Ta), 125W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	10-PolarPAK® (L)
Supplier Device-Gehäuse	10-PolarPAK® (L)
Verlustleistung (max)	5.2W (Ta), 125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)
Rds On (Max) @ Id, Vgs	1.6 mOhm @ 25A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	138nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	6100pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

SIE848DF-T1-E3 ist neu im Original, Suche SIE848DF-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIE848DF-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIE848DF-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIE844DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 44.5A POLARPAK</p>	 <p>SIE848DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE854DF-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 100V 60A POLARPAK</p>	 <p>SIE836DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 200V 18.3A POLARPAK</p>
 <p>SIE848DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE848DF-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE844DF-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 44.5A POLARPAK</p>	 <p>SIE854DF-T1-E3 Vishay / Siliconix MOSFET N-CH 100V 60A POLARPAK</p>

heiße Teile

Mehr

0603YA240JAT4A	1812HA101KAT1A	6MBP50RTM060	B82787C104H2J1	BD8305MUV-E2
CDBM1200-HF	CL-196YG-CD-T	DF2S6.8UCT	EE87C521	EL7222CS
FQPF16N25C	GRM1556T1H680GD01D	GRM31CC80J226KE19L	L2004F31	MB15E06SRPFT-G-BND-ERE1
MC33267D2TG	MRP24-0502	MSD7816-L2	NRF24Z1-REEL	PH300S280-28/PI
PS219B2-CS	S-812C34AMC-C20T2G	SI3477DV-T1-GE3	SIE01-03	SIE01-06
SIE20031	SIE20034	SIE501.8LT	SIE503.3LT	SIE503.3LTR
SIE800DF-T1-E3	SIE800DF-T1-E3	SIE802DF-T1-E3	SIE802DF-T1-E3	SIE808DF-T1-E3
SIE808DF-T1-E3	SIE812DF	SIE848DF-T1-E3	SIE862DF-T1-GE3	SIE862DF-T1-GE3
SIE864DP-T1-GE3	SIE874DF-T1-GE3	SIE874DF-T1-GE3	skiiip14NAB065V1	SMCJ36A-13-F
SN74AHC00PWLE	TL034AIN	UPA1763G-E1-A	VI-J6Y-CW	VKO55-16i07

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